

## PRELIMINARY

Notice: This is not a final specification  
Some parametric are subject to change.

〈SMALL-SIGNAL TRANSISTOR〉

## RTBN141AP1

TRANSISTOR WITH RESISTOR  
FOR SWITCHING APPLICATION  
SILICON NPN EPITAXIAL TYPE

### DESCRIPTION

RTBN141AP1 is a one chip transistor  
with built-in bias transistor.

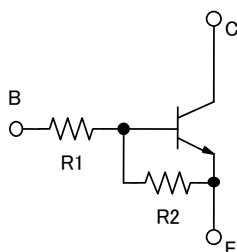
### FEATURE

- Built-in bias resistor ( $R1=10k\Omega$ ,  $R2=10k\Omega$ )
- High collector current ( $I_C=1A$ )
- Small package for easy mounting.

### APPLICATION

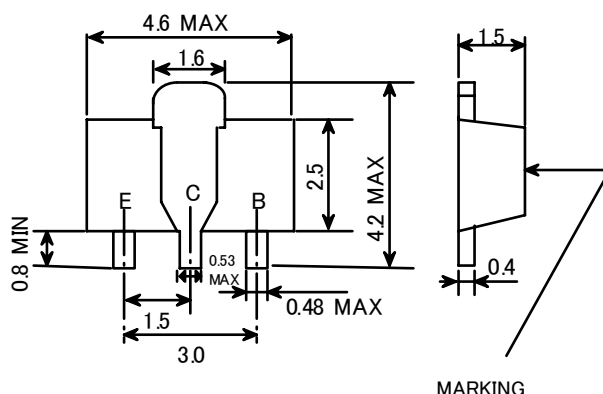
Switching.

### EQUAIVALENT CIRCUIT



### OUTLINE DRAWING

UNIT: mm



### TERMINAL CONNECTOR

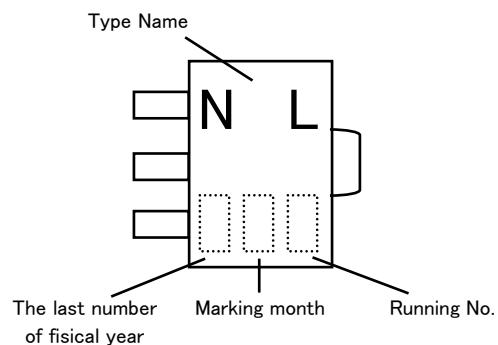
E: EMITTER  
C: COLLECTOR  
B: BASE

JEITA: SC-62  
JEDEC: SOT-89

### MAXIMUM RATING ( $T_a=25^\circ C$ )

| SYMBOL    | PARAMETER                                  | RATING   | UNIT       |
|-----------|--------------------------------------------|----------|------------|
| $V_{CBO}$ | Collector to Base voltage                  | 80       | V          |
| $V_{EBO}$ | Emitter to Base voltage                    | 10       | V          |
| $V_{CEO}$ | Collector to Emitter voltage               | 60       | V          |
| $I_C$     | Collector current                          | 1        | A          |
| $I_{CM}$  | Peak collector current                     | 2        | A          |
| $P_{CM}$  | Collector dissipation ( $T_a=25^\circ C$ ) | 500      | mW         |
| $T_j$     | Junction temperature                       | +150     | $^\circ C$ |
| $T_{stg}$ | Storage temperature                        | -55~+150 | $^\circ C$ |

### MARKING



### ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ C$ )

| SYMBOL       | PARAMETER                 | TEST CONDITIONS              | LIMITS |     |     | UNIT      |
|--------------|---------------------------|------------------------------|--------|-----|-----|-----------|
|              |                           |                              | MIN    | TYP | MAX |           |
| $I_{CBO}$    | Collector cut off current | $V_{CE}=60V$ , $I_E=0$       | —      | —   | 0.1 | $\mu A$   |
| $V_{I(on)}$  | Input on voltage          | $V_{CE}=0.2V$ , $I_C=0.1A$   | —      | —   | 5.0 | V         |
| $V_{I(off)}$ | Input off voltage         | $V_{CE}=5V$ , $I_C=100\mu A$ | 0.3    | —   | —   | V         |
| $h_{FE1}$    | DC forward current gain1  | $V_{CE}=2V$ , $I_C=0.1A$     | 200    | —   | —   | —         |
| $h_{FE2}$    | DC forward current gain2  | $V_{CE}=2V$ , $I_C=0.5A$     | 300    | —   | —   | —         |
| $h_{FE3}$    | DC forward current gain3  | $V_{CE}=2V$ , $I_C=1A$       | 200    | —   | —   | —         |
| R1           | Input resistor            | —                            | 7      | 10  | 13  | $k\Omega$ |
| R2           | Emitter-base resistor     | —                            | 7      | 10  | 13  | $k\Omega$ |



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**Keep safety first in your circuit designs!**

·ISAHAYA Electronics Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (1) placement of substitutive, auxiliary, (2) use of non-flammable material or (3) prevention against any malfunction or mishap.

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